

ANTREX Electronics

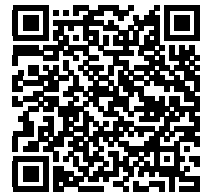
Electronic Components Sourcing Information

Product Reference Information

Part Number:	VS-19TQ015STRRPBF
Manufacturer:	Vishay General Semiconductor - Diodes Division
Package:	TO-263-3, D2PAK (2 Leads + Tab), TO-263AB
Availability:	Please confirm with sales

Product Page:

<https://antrexco.com/product/details/vishay-general-semiconductor-diodes-division-vs-19tq015strrpbf.html>



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Contact Information

Email: info@antrexco.com

WhatsApp: +86-186-8066-5326

Website: <https://antrexco.com>

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New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

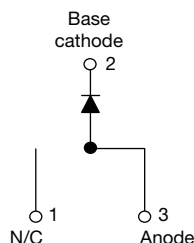
Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

High Performance Schottky Rectifier, 19 A


D²PAK


FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

PRODUCT SUMMARY

Package	D ² PAK
I _{F(AV)}	19 A
V _R	15 V
V _F at I _F	0.36 V
I _{RM} max.	522 mA at 100 °C
T _J max.	125 °C
Diode variation	Single die
E _{AS}	6.75 mJ

DESCRIPTION

The VS-19TQ015SPbF Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	19	A
V _{RRM}		15	V
I _{FSM}	t _p = 5 μs sine	700	A
V _F	19 A _{pk} , T _J = 75 °C	0.32	V
T _J	Range	-55 to +125	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-19TQ015SPbF	UNITS
Maximum DC reverse voltage	V _R	15	V
Maximum working peak reverse voltage	V _{RWM}		

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 80 °C, rectangular waveform	19	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	700	A
		10 ms sine or 6 ms rect. pulse	330	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.50 A, L = 6 mH	6.75	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 3 x V _R typical	1.50	A

**ELECTRICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	19 A	0.36	V
		38 A	0.46	
		19 A	0.32	
		38 A	0.43	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 100\text{ }^{\circ}\text{C}$, $V_R = 12\text{ V}$	465	mA
		$T_J = 100\text{ }^{\circ}\text{C}$, $V_R = 5\text{ V}$	285	
		$T_J = 25\text{ }^{\circ}\text{C}$	10.5	
		$T_J = 100\text{ }^{\circ}\text{C}$	522	
Maximum junction capacitance	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^{\circ}\text{C}$	2000	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R	10 000	V/ μ s

Note(1) Pulse width < 300 μ s, duty cycle < 2 %**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.50	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style D ² PAK	19TQ015S	

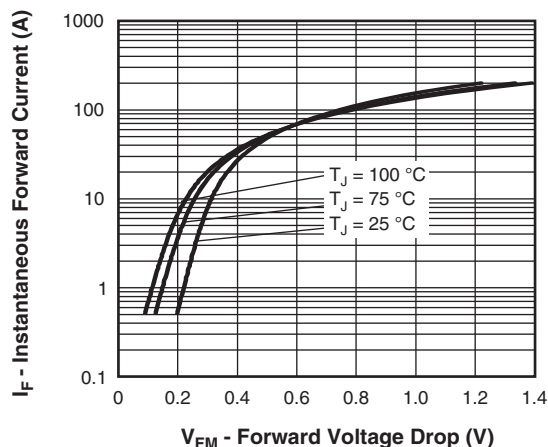


Fig. 1 - Maximum Forward Voltage Drop Characteristics

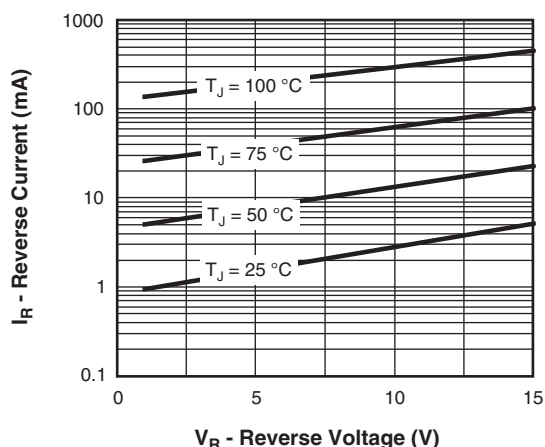


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

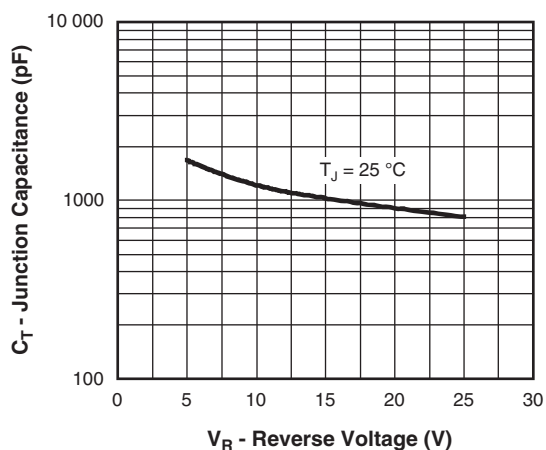


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

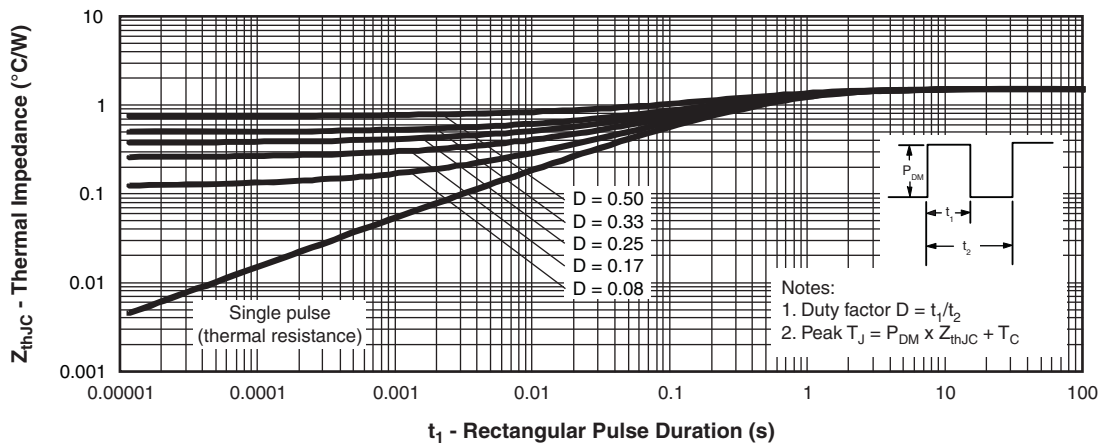


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

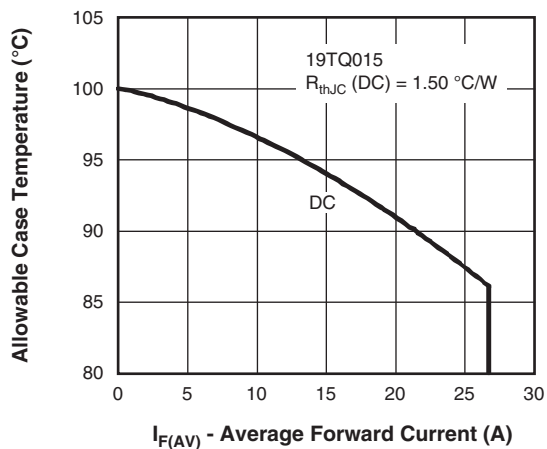


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

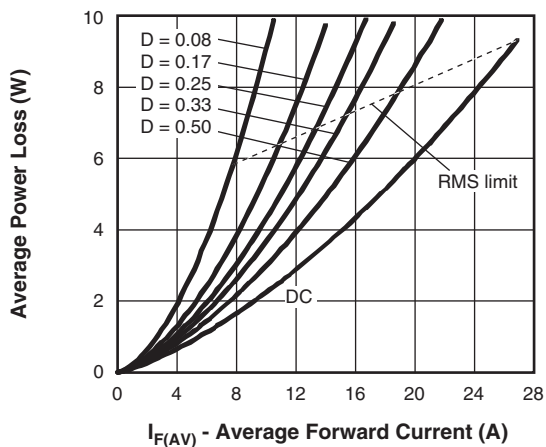


Fig. 6 - Forward Power Loss Characteristics

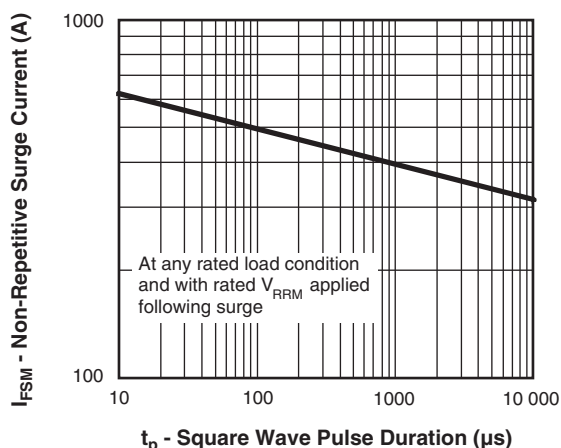


Fig. 7 - Maximum Non-Replicative Surge Current

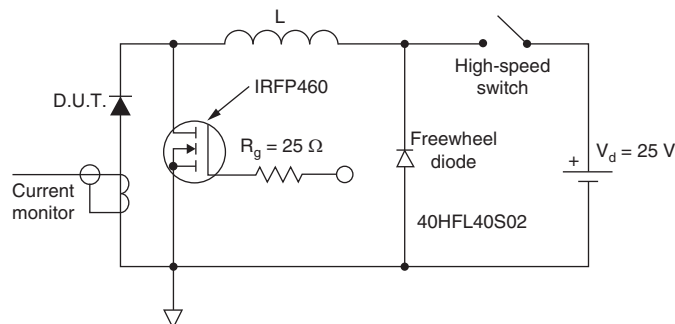


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE

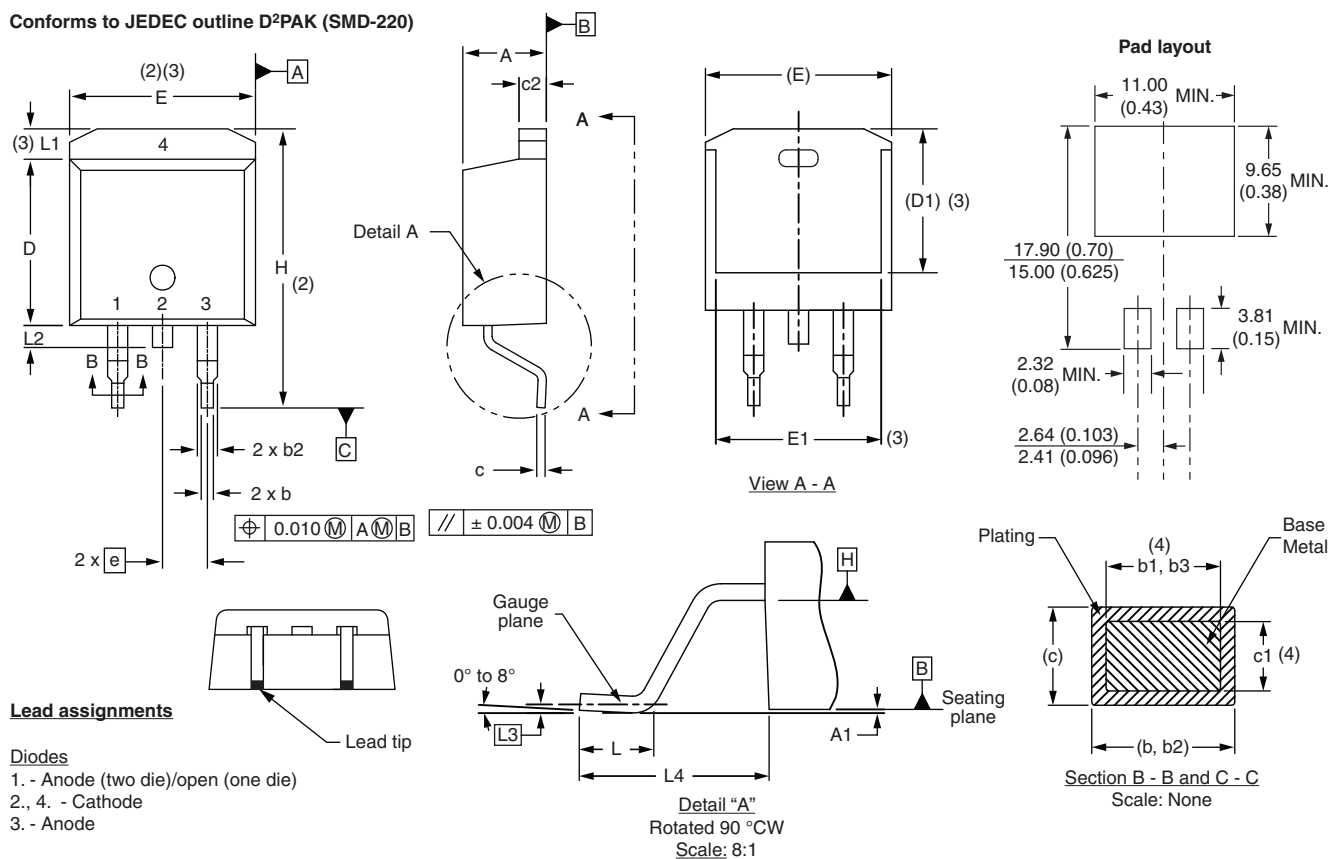
Device code	VS-	19	T	Q	015	S	TRL	PbF
	1	2	3	4	5	6	7	8
1	Vishay Semiconductors product							
2	Current rating (19 A)							
3	Circuit configuration: T = TO-220							
4	Schottky "Q" series							
5	Voltage rating (015 = 15 V)							
6	S = D ² PAK							
7	- None = tube (50 pieces) - TRL = tape and reel (left oriented) - TRR = tape and reel (right oriented)							
8	PbF = lead (Pb)-free							

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?96005

D²PAK, TO-262

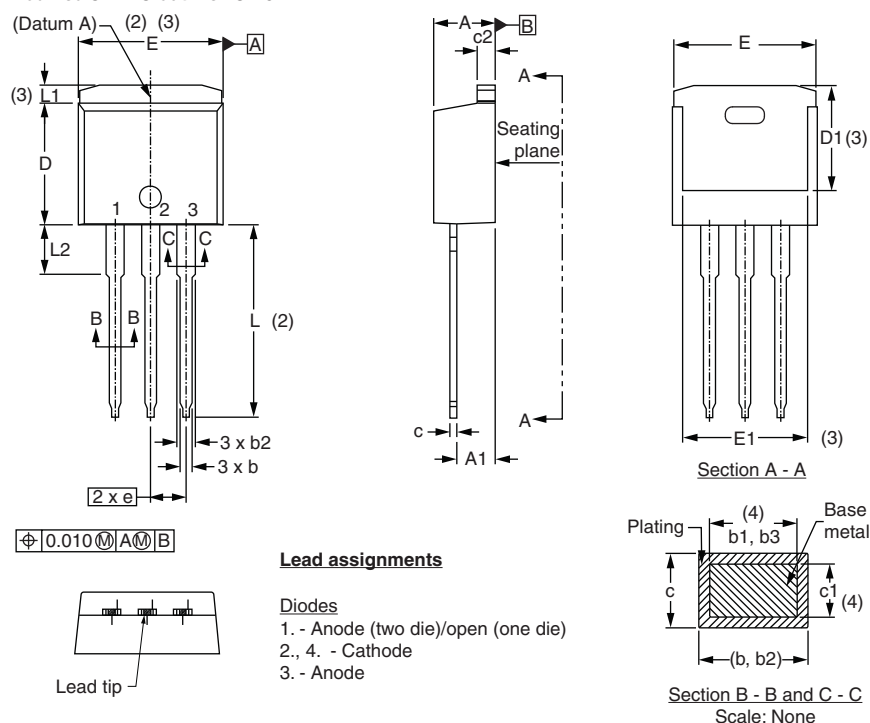
DIMENSIONS - D²PAK in millimeters and inches

Conforms to JEDEC outline D²PAK (SMD-220)



DIMENSIONS - TO-262 in millimeters and inches

Modified JEDEC outline TO-262



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
c	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
e	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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